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"Substitution in Ce_2TSi_3 Intermetallic Compositions with
 $\text{T} = (\text{Cr, Mn, Fe, Co, or Ni})_x(\text{Pd or Au})_{1-x}$ "

by

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Substitution in Ce_2TSi_3 Intermetallic Compositions with $\text{T} = (\text{Cr, Mn, Fe, Co, or Ni})_x(\text{Pd or Au})_{1-x}$

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Abstract

Alloys of composition $\text{Ce}_2(3d/\text{T})\text{Si}_3$, with "3d" one of Cr, Mn, Fe, Co or Ni and "T" being Pd or Au, were prepared and examined by powder x-ray diffraction. Select single phase compositions were further examined by magnetic susceptibility, by resistivity for the Pd and Co end-members and by specific heat for Ce_2CoSi_3 . For compounds not containing cobalt, effective cerium moments consistent with trivalent cerium were observed. A re-examination of the AlB_2 related structure of Ce_2CoSi_3 by single crystal methods revealed ordering of cobalt within the CoSi_3 hexagonal layer. Magnetic susceptibility, resistance and specific heat measurements suggest valence fluctuation behavior of the cerium in Ce_2CoSi_3 . A return to trivalent cerium magnetic behavior occurs on increasing palladium or gold substitution for cobalt.

Keywords: cerium intermetallic, valence fluctuation, magnetic susceptibility

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Introduction

Certain structure types allow considerable substitution of isoelectronic or aleovalent elements without a change in structure. Perhaps the most well-known structure type which exhibits this flexibility is that of ThCr_2Si_2 . Cerium-based silicide versions of this composition are known for transition elements Mn through Cu, Ru through Ag and Os through Au [1, 2]. Germanium, arsenic and phosphorous variants in place of Si are also known for some of these transition elements [1, 2].

The ability to substitute extensively in a cerium intermetallic allows some measure of control over electron count and over the variety of atoms in the co-ordination environment of the cerium. If the substitution is by the alloying of elements, some randomness in the type of near-neighbours may be present, unless the alloyed elements order, but the co-ordination number and geometry do not change dramatically. The ability to adjust electron count may allow the Fermi level in such a material to be moved closer in energy to the cerium $4f^1$ energy level. Alloying may also change the character and overlap of the states near the Fermi level. Both may encourage the formation of a fluctuating or intermediate valence state of the cerium. It is with this in mind that we examine the effects of alloying transition metals (T) in " Ce_2TSi_3 " compositions.

Numerous ternary rare earth and actinide compounds have been reported with atomic ratios of 2:1:3 [3-8] and adopt variants of either the tetragonal $\alpha\text{-ThSi}_2$ or hexagonal $\beta\text{-ThSi}_2$ (AlB_2) structure types [1] (Fig. 1). Several ordered variants of the AlB_2 structure type are also known: Er_2RhSi_3 ($2a$, $2c$)[3, 5], Lu_2CoGa_3 ($2a$, $2c$)[5] and U_2RuSi_3 ($2a$, c)[8]. The type of hexagonal ordering is given in parenthesis and refers to how the ordering has resulted in multiplication of the lattice constants of the AlB_2 structure type. Cerium-transition element-silicides with a 2:1:3 stoichiometry are reported for $T = \text{Co}$ [10], Ni [11], Cu [12] and Rh [3]. An iron version was reported [13] but was not detected in later attempts [14, 15]. The series

Ln_2PdSi_3 is known for $\text{Ln} = (\text{Pr}, \text{Nd}, \text{Gd}, \text{Tb}, \text{Dy}, \text{Ho}, \text{Er}, \text{Tm} \text{ and } \text{Y})$ [4], adopting the Er_2RhSi_3 structure type, but a cerium member of the series was not reported. Our current study has focused on substitution between the mid to late 3d elements and palladium or gold in $\text{Ce}_2(3\text{d}/\text{M})\text{Si}_3$. These larger 4d and 5d elements are chemically very distinct from the 3d elements (apart from some Ni/Pd familial relationship) and may illustrate structural tolerance in terms of different bonding characteristics as well as electron count more so than 3d/3d alloying.

Experimental

Samples were prepared by arc-melting elements of at least 99.9% purity in the desired atomic ratio. Samples to be annealed were placed in sections of tantalum tubing, then sealed in evacuated quartz tubes. Annealing temperature and duration varied between samples depending on composition and is discussed further below. Samples were all silver-metallic in appearance, stable in air over a time-scale of months and extremely brittle.

Powder diffraction data on both as cast and annealed material were collected on a SCINTAG $\theta/2\theta$ Diffractometer using $\text{Cu K}\alpha_1$ radiation and Al_2O_3 as an internal standard. Powder diffraction patterns were indexed using the program TREOR90 [16] and the lattice parameters obtained thereby were refined by a least-squares technique. Single crystal diffraction data on Ce_2CoSi_3 were collected on a Rigaku AFC7R diffractometer using graphite monochromated $\text{Mo K}\alpha$ radiation from a 12kW rotating anode source and again on a P4 automatic 4-circle diffractometer with a sealed tube source (stationary anode) and graphite monochromated $\text{Mo K}\alpha$ radiation. Magnetic susceptibility data were collected by the Faraday technique and fit to a Curie-Weiss expression, when appropriate, as described elsewhere [17]. Resistance data were obtained by a 4-probe technique. Specific heat measurements on Ce_2CoSi_3 were performed by a time constant technique [18].

Results and Discussion

Structural Behavior

Before commencing the alloy study, we attempted to prepare the Pd and Au containing end members. The powder diffraction pattern for as cast Ce_2PdSi_3 could be indexed on an hexagonal cell with $a = 4.131\text{\AA}$ and $c = 4.283\text{\AA}$. After annealing for 2 weeks (one sample) or 5 weeks (second sample) at 750°C , several small peaks appeared which could be indexed on an hexagonal cell with twice the as cast a and four times the as cast c . This suggests that annealed Ce_2PdSi_3 may be a new ordered variant ($2a$, $4c$) of the AlB_2 structure type (Table 1). The powder diffraction patterns of as cast samples of composition " Ce_2AuSi_3 " could be readily indexed to a tetragonal cell with $a = 4.222\text{\AA}$ and $c = 14.375\text{\AA}$ but such samples always became two-phase with an hexagonal phase (Table 2) dominant after anneal at temperatures varying from 750°C to 1100°C . For these temperatures, the 2:1:3 composition in the Ce-Au-Si system appears to lie between two solid solution regions: one tetragonal (approaching CeSi_2), the other hexagonal.

Tables 1 and 2 summarise the results of powder X-ray diffraction pattern analyses for samples containing 3d/Pd alloying and 3d/Au alloying, respectively, in $\text{Ce}_2(3\text{d}/\text{M})\text{Si}_3$. Annealing of nickel-containing samples was done at 750°C for 5 weeks. A shorter anneal time of 2 weeks was used for all other samples by increasing the anneal temperature to 900°C . It was necessary to anneal gold-rich Co/Au compositions an additional 2 weeks at 900°C to minimize the amount of second phase present in the powder diffraction pattern. Estimates of second phase content are given as the ratio of the most intense unindexed diffraction peak to the most intense indexed peak, expressed as a percentage. For samples that appeared tetragonal as cast and hexagonal after anneal, the major peak from the residual tetragonal phase overlaps the major peak of the hexagonal phase. In this case, the impurity content was estimated from lesser peaks in the powder diffraction patterns.

Both nickel and cobalt appear to form complete solid solutions with palladium in a Ce_2TSi_3 composition (Fig. 2) and extensive solid solutions with Au (Fig. 3). The earlier 3d transition elements do not form solid solutions over as broad a range. From Table 1, however, we note that there are still some phases present in the powder diffraction patterns for the earlier 3d element substitutions with unit cells similar to the nickel and cobalt substitutions. The lattice parameters for these phases do change on increasing 3d content. For the cell parameters and impurity phase content in the powder diffraction data to keep changing with increasing substitution, there must be some solid solution region in the quaternary phase diagrams. The $\text{Ce}_2\text{M}_x\text{Pd}_{1-x}\text{Si}_3$ composition may lie within the boundary of such a region in a palladium rich section but, for increasing x , the $\text{Ce}_2\text{M}_x\text{Pd}_{1-x}\text{Si}_3$ composition may exit the single-phase region. Provided that the terminus of the region has not been passed, then the observed AlB_2 -related (defect) phases must exist on the boundary and change, after anneal, as the overall composition changes.

Upon observing hexagonal cells for cobalt rich $\text{Ce}_2\text{Co}_x(\text{Pd,Au})_{1-x}\text{Si}_3$ compositions that suggest a $2a,c$ variant of the AlB_2 structure, the structure of the cobalt parent, Ce_2CoSi_3 , was re-examined. Initial reports [10] on this material gave an AlB_2 cell with Co and Si disordered on the boron positions. The (1 0 0) and (1 1 0) were the strongest observed superlattice peaks, being approximately 6% of the intensity of the most intense (2 0 1) diffraction peak in $\text{Ce}_2\text{Co}_{0.5}\text{Au}_{0.5}\text{Si}_3$. By following the positions of these and other superlattice peaks in powder diffraction with increasing cobalt content, weak peaks in the powder diffraction pattern of Ce_2CoSi_3 could be identified near the 1% relative intensity level consistent with a doubling of the a lattice parameter of the reported cell. Such weak peaks could have easily been missed in earlier studies of Ce_2CoSi_3 [10, 15] if samples were not annealed sufficiently or if low signal-to-noise ratios were present. A single crystal study was pursued to examine the structure further.

Shards isolated from a crushed bead of composition Ce_2CoSi_3 were examined on a Rigaku AFC7R diffractometer using a 12kW rotating anode source until a crystal suitable for study was found. Data collected on this instrument and crystal could be solved and refined to a wR_2 of 1.6% but with a GooF of 3.18 and non-positive definite cerium thermal parameters. This was unsatisfactory, and was attributed to an absorption correction problem. A further data set was collected on a P4 automatic 4-circle diffractometer. The absorption correction was done by psi-scan methods on this dataset. The structural solution from this dataset was acceptable, with the thermal parameters of all atoms positive definite.

The choice of Laue class based on the *Laue* routine in the XSCANS [19] software used in data collection on the P4 was 6/mmm. Analysis using the program XPREP [20], however, suggested possible space groups of P-3m1 and P6/mmm. Solutions in both space groups were examined but yielded similar results, as discussed below. A final choice of the higher symmetry P6/mmm (No. 191) space group was made after comparing the two refinements.

Starting atomic positions were determined using the programs SIR92 [21] and XS [20]. The SIR92 program would refine in P-3m1 with a residual of 3.5% but would not refine in P6/mmm below 60%. No difficulty was encountered using the XS program to determine starting atomic positions. Subsequent refinement of positions and thermal parameters was done using the program XL [20] with anisotropic thermal parameters for all atoms. The difference made by choice of space group (P-3m1 versus P6/mmm) occurs in the z atomic positions for Co and Si. In P-3m1, z_{Si} was 0.5004(5) and z_{Co} was 0.4998(3). Within error, these values are equivalent to $z = 0.5$ obtained using P6/mmm, hence the choice of P6/mmm. Residuals for all data in P-3m1 were $R_1 = 0.0334$ and $wR_2 = 0.0554$ and the GooF was 1.278. These residuals are slightly higher than for P6/mmm (Table 3) and the GooF is slightly lower. Some ambiguity in the choice of spacegroup may remain, however, due to the weak nature of the superlattice reflections. A final difference Fourier synthesis in P6/mmm revealed no significant residual

peaks greater than $+0.634$ or -0.705 $e/\text{\AA}^3$. Details of the single crystal data collection and structure refinement in $P6/mmm$ are given in Table 3. Refined atomic positions for space group $P6/mmm$ are listed in Table 4. Interatomic distances from the single crystal refinement are given in Table 5.

The structure of Ce_2CoSi_3 is indeed related to the U_2RuSi_3 type [8] as a $2a,c$ variant on the AlB_2 structure type (Fig. 4). Cobalt and silicon form ordered two-dimensional hexagonal networks separated by cerium. In the report on the prototype U_2RuSi_3 structure, the silicon atoms (half) occupy a split position ($12o$, $x = 0.166$, $y = 2x$, $z = 0.4432$) but in Ce_2CoSi_3 , the silicon atoms are coplanar with the cobalt atoms. Silicon-silicon and cobalt-silicon distances in Ce_2CoSi_3 (Table 5), at 2.387\AA and 2.292\AA , are comparable to Si-Si and T-Si distances in Er_2RhSi_3 [5] ($d_{\text{Si-Si}} = 2.345\text{\AA}$, $d_{\text{Rh-Si}} = 2.351\text{\AA}$). The Si-Si distance is also comparable to that in α -Si, 2.352\AA [22], while the Co-Si distance is comparable to the sum of the respective covalent radii, 2.27\AA [23]. These distances are also comparable to those in CeCoSi_2 ($d_{\text{Co-Si}} = 2.29\text{\AA} - 2.34\text{\AA}$, $d_{\text{Si-Si}} \geq 2.44\text{\AA}$) [24-26]. Cerium-near neighbour distances in Ce_2CoSi_3 are comparable to or slightly larger than those in CeCoSi_2 . Cerium-silicon distances are 3.178\AA (Ce1-Si) and 3.125\AA (Ce2-Si), compared to a range from 3.07\AA to 3.19\AA in CeCoSi_2 . The Ce2-Co distance is 3.143\AA and slightly larger than the cerium-cobalt distance in CeCoSi_2 (3.12\AA).

Magnetic and Electric Behavior

The magnetic susceptibilities for select compositions were examined as a function of temperature. In particular, the magnetic behavior of the substitutions involving cobalt were examined since the variations in cell volume as a function of cobalt content (Figs. 2, 3) for both $\text{Ce}_2\text{Co}_x\text{Pd}_{1-x}\text{Si}_3$ and $\text{Ce}_2\text{Co}_x\text{Au}_{1-x}\text{Si}_3$ exhibit deviations from linearity for high cobalt content.

This suggests a possible loss or reduction in the cerium moment for the cobalt-rich compositions. Table 6 lists the magnetic data for the compositions examined.

For Ce_2PdSi_3 , the inverse magnetic susceptibility (Fig. 5) was measured on ground material (powder). We have previously [17] measured ground material and observed re-orientation of the powder on cooling from the action (torque) of an applied field on an anisotropic magnetic moment. We have done so here as well to obtain a qualitative estimate of the anisotropy in the cerium moment in these silicide materials. This re-orientation usually manifests as a discontinuity in the cooling data, with the orientation of the powder remaining fixed on warming, as observed at 24K in the inset to Figure 5. Since the starting material was polycrystalline, complete orientation of all single crystal grains is not assured, however, the anisotropy appears to be small. Fitting the susceptibility data collected on warming above 100K yields an effective moment per cerium of $2.48(2)\mu_B$, consistent with a free ion value of $2.54\mu_B$, and a θ of 7(1)K, suggesting weak ferromagnetic exchange.

Below 10K, the inverse susceptibility versus temperature decreases in slope and appears to almost plateau by 4.2K with χ^{-1} approximately 7.15 mole Ce/emu. This may indicate some ordered magnetic state. At 4.2K and an applied field of 10.1kG, we calculate an ordered moment of $0.25\mu_B$ per Ce. This is much reduced from a moment calculated from the product of the Landé factor, g (6/7), and angular momentum, J (5/2), for Ce ($gJ = 2.21\mu_B$) or for a crystal field split cerium moment ($0.7\mu_B$ and $1.3\mu_B$ being typical measured values). At 4.2K then, Ce_2PdSi_3 is not likely to be a completely ordered ferromagnetic material. It may be that 4.2K is not sufficiently far below T_C to give the maximum moment, or perhaps some more complicated spin structure is present.

The resistivity of Ce_2PdSi_3 is shown in Figure 6 as a function of temperature from 4.2K to 300K. Some hysteresis on warming is evident and may be due to contact problems or some gradual change in contact between grain boundaries. These silicide materials are all brittle

intermetallics and observations of cracks on the surfaces of arc-melted beads often indicate the presence of some cracks within the material. No large discontinuities are present in the resistivity to suggest continued cracking on cooling in this sample. It would be prudent, however, to interpret the magnitude of the resistivity as only an upper limit on the absolute value. The overall behavior is that of a metallic system with a decrease in resistivity below 100K corresponding to a decrease in magnetic scattering from thermally depopulating crystal-field-split cerium 4f states. A decrease in resistivity is also apparent below 10K, coincident with the noted behavior in the susceptibility.

The temperature dependent inverse magnetic susceptibilities for the other materials listed in Table 6 are given in Figure 7 for Pd- and Ni- containing materials and in Figure 8 for Co/Au alloy samples. The behavior of Ce_2NiSi_3 is consistent with that previously reported [15] with an effective high temperature moment of $2.48(1)\mu_B$ per cerium and θ of $-22(2)\text{K}$ compared to the reported moment of $2.46\mu_B$ and θ of -18K . The behavior of the cobalt containing compounds is more complicated.

While the temperature dependence of the magnetic susceptibility of the cobalt-substituted materials can be fit to a Curie-Weiss expression, it may be inappropriate to do so for the more cobalt-rich samples. With increasing cobalt content, we observe an increase in χ^{-1} corresponding to a decrease in magnetisation. There is still some roughly linear dependence of the inverse susceptibility on temperature above 100K for most samples (perhaps above 250K for Ce_2CoSi_3), but the increasingly negative θ (Table 6) values most likely do not result from anti-ferromagnetic interactions. Most of these cobalt-containing materials exhibit large increases in magnetisation below 100K. The exception is the cobalt end-member which plateaus below 80K and has what may be a small Curie tail from small amounts ($<1\%$) of impurities not observed in powder diffraction data. A small deviation near 5K in this tail may indicate ordering in this possible second phase. It may also be possible for some cerium moments in Ce_2CoSi_3 to be present, as

will be discussed below. The ternary compounds CeRhIn [27] and Ce₂Ni₃Si₅ [28] exhibit similar behavior in their susceptibilities (plateauing at low temperature, non-magnetic behavior). The resistivities of these two materials are also similar in temperature dependence to that for Ce₂CoSi₃ (Fig. 9) with a roughly flat region at high temperature and broad decrease on cooling. In [27] and [28], this type of behavior was attributed to interconfiguration fluctuations (ICF) of the cerium as described by Hirst [29] and Sales et al. [30]. Both CeCoSi₂ [27] and CeCoSi₃ [31] exhibit Pauli paramagnetic behavior with some weak temperature dependence that has also been described, in the case of CeCoSi₃, as spin fluctuations in an ICF model [31].

Specific heat data below 20K were collected on Ce₂CoSi₃ and are plotted as C/T versus T^2 in Figure 10. The behavior of C/T above 10K is roughly linear and extrapolates to a C/T value at $T = 0$ K of $\gamma = 59.7 \text{ mJ/mol-Ce} \cdot \text{K}^2$. The actual data deviates from linearity below 10K. A small feature near 5K is also present, as in the susceptibility. The data below this feature tend toward an intercept of $71.5 \text{ mJ/mol-Ce} \cdot \text{K}^2$. Both of the values are comparable to other valence fluctuation materials [28].

When discussing the trend in magnetic behavior in the series U₂TSi₃, in particular with T one of Fe, Ru or Os, Chevalier et al. [32] considered the interaction between the *nd* orbitals on the transition element with the 5f orbitals on uranium. Given that the 4f orbitals of cerium are more localised than the 5f orbitals of uranium, we consider an alternate interpretation of the magnetic behavior in the series Ce₂TSi₃. In changing structure from CeCoSi₃ [31] (ordered BaAl₄ type, variant BaNiSn₃) to CeCoSi₂ (CeNiSi₂ type described as alternating BaAl₄ and AlB₂ [25]) to Ce₂CoSi₃ (ordered AlB₂), the cerium-silicon near neighbour distances increase from a range of 3.01Å - 3.16Å in CeCoSi₃ through a range of 3.07Å-3.19Å in CeCoSi₂ to a range of 3.125Å-3.178Å in Ce₂CoSi₃. The cerium-cobalt distances vary from 3.28Å to 3.12Å to 3.14Å, respectively, decreasing, but not as steadily as the increase in the minimum cerium-silicon distances. The average near-neighbour distance does appear to be increasing. Overlap of orbitals

on near-neighbour atoms with cerium orbitals and cerium 5d orbitals in particular will depend on the cerium-near neighbour distance and geometry and may lead to a band near the Fermi level with appreciable cerium 5d character if strong overlap is present. If additional stabilisation energy of the material can be achieved by promoting the 4f electron on each cerium into this band (i.e. if the effective energy of the $6s^2 5d^2 4f^0$ band state becomes lower than that of the $6s^2 5d^1 4f^1$ state with localised f-electron and delocalised d-electron), then the cerium atoms will have non-magnetic ground states. If the energies of the two configurations are not too disparate, then the electron may hop between the two states (interconfiguration fluctuations [33]). As the cerium-near neighbour distance is increased in going from CeCoSi_3 to Ce_2CoSi_3 - in essence, this is the opposite of applying pressure - we decrease the overlap with the cerium 5d orbitals. This would decrease the 3p-5d bandwidth and raise the effective energy of the $5d^2 4f^0$ electrons, decreasing the effective separation between the d electrons and $5d^1 4f^1$ states on each cerium.

In Ce_2CoSi_3 , the ground state is still non-magnetic, but the energy separation between the two states ($5d^2$ and $5d^1 4f^1$) in this model would be small. We must also consider the effect of having two crystallographically distinct cerium sites (Table 5). At the corners of the unit cell (Fig. 4), the Ce1 atoms are co-ordinated by 12 silicon atoms all at a distance of 3.178Å. Three-quarters of the cerium atoms in the unit cell are Ce2, however, and are co-ordinated at shorter distances by 8 Si ($d_{\text{Ce2-Si}} = 3.125\text{Å}$) and 4 Co ($d_{\text{Ce2-Co}} = 3.143\text{Å}$). This could lead to different and perhaps weaker interactions for Ce1. It is possible that the low temperature "tail" in the susceptibility is a reflection of having 1/4 of the cerium atoms in Ce_2CoSi_3 with a weakly magnetic ground state (perhaps with some Ce1-Ce1 exchange interaction perpendicular to the hexagonal layers leading to magnetic ordering near 5K). Such speculation, however, suggests that further study of Ce_2CoSi_3 at low temperatures is required.

Upon substituting the larger transition elements Pd and Au, the Ce-Si distances increase (obvious from increased *a* and *c* lattice parameters, Tables 1 and 2), the valence electron count

increases, and disorder is induced in the Ce2 environment. Increased separation and electron count will lead to less overlap and a narrowing and greater filling of any band based on this overlap. Disorder in the Ce2 environment could lead to magnetically inequivalent ground states for individual Ce2 atoms, depending on type and number of each transition element near-neighbour, similar to the discussion above for Ce1 versus Ce2. The net effect is an increase in magnetisation as the cobalt content decreases, particularly at low temperature as magnetic ground states become favoured. There is a corresponding decrease in spin fluctuations as the magnetic ground state becomes more favoured. This is reflected in the decreasing magnitude of the θ values (Table 6) and the apparent return to well-developed 4f¹ cerium behavior for $x \leq 0.5$ in $\text{Ce}_2\text{Co}_x(\text{Pd or Au})_{1-x}\text{Si}_3$.

Conclusions

Limited flexibility in substitution does exist in Ce_2TSi_3 but is more extensive for the later transition elements Co and Ni when alloying with Pd or Au than for the earlier 3d elements Cr, Mn and Fe. In particular, extensive substitution can be done between Co and Pd or Au in Ce_2CoSi_3 . The structure of Ce_2CoSi_3 was re-examined and found to an ordered variant of the AlB_2 structure. A transition from valent fluctuating to trivalent cerium behavior is observed with decreasing cobalt content in $\text{Ce}_2\text{Co}_x(\text{Pd or Au})_{1-x}\text{Si}_3$. This was attributed to decreasing Ce-Si interactions as the incorporation of the larger transition element increased the lattice spacings and hence the Ce-Si distances.

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Table 1

Cell parameters, reduced AlB_2 cell volume and the ratio of the largest unindexed peak (estimated if overlapping, see text) to the largest indexed peak (the 2 0 1 peak for the $2a$, c ordered variant of AlB_2) for $\text{Ce}_2\text{M}_x\text{Pd}_{1-x}\text{Si}_3$ compositions.

Material	Symmetry	$a/\text{\AA}$	$c/\text{\AA}$	$V/\text{\AA}^3$ (cell)	$V/\text{\AA}^3$ (AlB_2)	$I_{\text{imp}}/I_{\text{max}}$ (%)	Ref./ note
$\text{Ce}_2\text{Ni}_x\text{Pd}_{1-x}\text{Si}_3$							
$x = 0$	hex.	8.2631(5)	17.132(2)	1013.0(1)	63.31	--	
$x = 0.2$	"	8.2274(8)	17.118(4)	1003.5(3)	62.72	--	
$x = 0.4$	"	8.1908(7)	17.114(3)	994.3(2)	62.15	--	
$x = 0.6$	hex.	4.0776(4)	4.2816(4)	61.65(1)	61.65	--	
$x = 0.8$	"	4.0589(3)	4.2795(3)	61.06(1)	61.06	--	
$x = 1$	"	4.0406(4)	4.2801(5)	60.52(1)	60.52	--	
$\text{CeNi}_{0.5}\text{Si}_{1.5}$	"	4.048	4.291	60.89	60.89		[14]
$\text{CeNi}_{0.53}\text{Si}_{1.47}$	"	4.039	4.287	60.56	60.56		[10]
$\text{CeNi}_{0.4}\text{Si}_{1.6}$	"	4.034	4.294	60.51	60.51		[13]
$\text{Ce}_2\text{Co}_x\text{Pd}_{1-x}\text{Si}_3$							
$x = 0.2$	hex.	8.2318(9)	4.2709(7)	250.63(6)	62.65	1	
$x = 0.4$	"	8.2009(7)	4.2586(5)	248.04(4)	62.01	< 1	
$x = 0.5$	"	8.1869(5)	4.2494(4)	246.66(3)	61.66	--	
$x = 0.6$	"	8.1714(6)	4.2442(4)	245.42(3)	61.36	--	
$x = 0.8$	"	8.1376(6)	4.2249(4)	242.30(3)	60.57	--	
$x = 0.9$	"	8.1161(7)	4.2100(5)	240.16(4)	60.04	--	
$x = 1.0$	"	8.0967(7)	4.1959(5)	238.22(4)	59.56	--	
$\text{CeCo}_{0.5}\text{Si}_{1.5}$	"	4.044	4.194	59.40	59.40		[9]
$\text{CeCo}_{0.4}\text{Si}_{1.6}$	"	4.046	4.266	60.48	60.48		[13]
$\text{CeCo}_{0.4}\text{Si}_{1.6}$	"	4.055	4.226	60.18	60.18		[14]
$\text{Ce}_2\text{Fe}_x\text{Pd}_{1-x}\text{Si}_3$							
$x = 0.25$	hex.	8.2414(9)	4.2674(7)	251.01(6)	62.75	1	
$x = 0.5$	"	8.2229(9)	4.252(1)	248.96(7)	62.24	4	
$x = 0.75$	"	4.0978(5)	4.2431(5)	61.70(1)	61.70	10	
$x = 1$	"	4.062(2)	4.212(4)	60.19(7)	60.19	26	
Ce_2FeSi_3	"	4.065	4.191	59.97	59.97		[11]
$\text{CeFe}_{0.4}\text{Si}_{1.6}$	"	4.058	4.265	60.82	60.82		[13]
$\text{CeMn}_x\text{Pd}_{1-x}\text{Si}_3$							
$x = 0.25$	hex.	8.2573(7)	17.113(3)	1010.5(2)	63.16	1	
$x = 0.5$	tetrag.	4.1806(6)	14.294(3)	249.82(7)	[62.5]	4	as cast
$x = 0.5$	hex.	4.1140(7)	4.2700(7)	62.59(1)	62.59	(15)	annealed
$x = 0.75$	tetrag.	4.1804(4)	14.177(2)	247.75(5)	[61.9]	16	annealed
$\text{Ce}_2\text{Cr}_{0.5}\text{Pd}_{0.5}\text{Si}_3$	"	4.1823(8)	14.259(3)	249.41(9)	[62.4]	9	as cast
$\text{Ce}_2\text{Cr}_{0.5}\text{Pd}_{0.5}\text{Si}_3$	hex.	4.1130(4)	4.2779(5)	62.67(1)	62.67	(30)	annealed

Table 2

Cell parameters, reduced AlB_2 cell volume and the ratio of the largest unindexed peak (estimated if overlapping) to the largest indexed peak (the 2 0 1 peak for the $2a$, c ordered variant of AlB_2) for $\text{Ce}_2\text{M}_x\text{Au}_{1-x}\text{Si}_3$ compositions.

Material	Symmetry	$a/\text{\AA}$	$c/\text{\AA}$	$V/\text{\AA}^3$ (cell)	$V/\text{\AA}^3$ (AlB_2)	$I_{\text{imp}}/I_{\text{max}}$ (%)	Note
$\text{Ce}_2\text{Ni}_x\text{Au}_{1-x}\text{Si}_3$							
$x = 0$	tetrag.	4.2224(3)	14.375(1)	256.34(3)	[64.1]	--	as cast
$x = 0$	hex.	8.284(1)	8.701(1)	517.1(1)	64.64	(30)	annealed
$x = 0.1$	"	4.1264(5)	4.3459(6)	64.08(1)	64.08	1	
$x = 0.25$	"	4.1108(5)	4.3373(6)	63.47(1)	63.47	< 1	
$x = 0.5$	"	4.0917(4)	4.3226(6)	62.67(1)	62.67	--	
$x = 0.75$	"	4.0680(4)	4.3034(5)	61.68(1)	61.68	--	
$x = 1$	"	4.0406(4)	4.2801(5)	60.52(1)	60.52	--	
$\text{Ce}_2\text{Co}_x\text{Au}_{1-x}\text{Si}_3$							
$x = 0.2$	hex.	8.2408(7)	8.6816(8)	510.59(8)	63.82	1	
$x = 0.4$	"	4.1055(2)	4.3157(4)	63.00(1)	63.00	1	
$x = 0.5$	"	8.1995(8)	4.3028(5)	250.53(5)	62.63	< 1	
$x = 0.6$	"	8.1761(9)	4.2862(5)	248.14(5)	62.03	--	
$x = 0.8$	"	8.1445(7)	4.2479(5)	244.02(4)	61.01	--	
$x = 0.9$	"	8.1180(7)	4.2222(6)	240.97(5)	60.24	--	
$x = 1$	"	8.0967(7)	4.1959(5)	238.22(4)	59.56	--	
$\text{Ce}_2\text{Fe}_x\text{Au}_{1-x}\text{Si}_3$							
$x = 0.25$	hex.	4.1232(3)	4.3275(5)	63.71(1)	63.71	< 1	
$x = 0.5$	"	8.2275(7)	4.2965(4)	251.88(4)	62.97	3	
$x = 0.75$	"	8.1953(8)	4.2669(5)	248.19(4)	62.05	8	
$x = 1$	"	4.062(2)	4.212(4)	60.19(7)	60.19	26	
$\text{Ce}_2\text{Mn}_x\text{Au}_{1-x}\text{Si}_3$							
$x = 0.5$	tetrag.	4.2031(4)	14.274(1)	252.17(4)	[63.0]	4	annealed
$\text{Ce}_2\text{Cr}_x\text{Au}_{1-x}\text{Si}_3$							
$x = 0.5$	tetrag.	4.2087(3)	14.256(1)	252.52(3)	[63.1]	9	annealed

Table 3Crystal and structure refinement data for Ce_2CoSi_3 .

Empirical formula	Ce_2CoSi_3
Formula weight	423.44
Temperature	293(2) K
Wavelength	0.71069 Å
Crystal system	Hexagonal
Space group	P6/mmm (No. 191)
Unit cell dimensions	$a = 8.104(2)$ Å $c = 4.197(2)$ Å
Volume, Formula units	$238.7(1)$ Å ³ , 2
Density (calculated)	5.891 g/cm ³
Absorption co-efficient	22.738 mm ⁻¹
F(000)	370
Crystal size	0.10 x 0.10 x 0.05 mm ³
Theta range for data collection	2.90° to 29.91°
Limiting indices	$-3 \leq h \leq 7, -5 \leq k \leq 9, -5 \leq l \leq 5$
Reflections collected	1398
Independent reflections	172 [$R_{\text{int}} = 0.0494$]
Reflections with $I > 2\sigma(I)$	142 [$R_{\sigma} = 0.0309$]
Absorption correction	From ψ -scan data
Max. and min. transmission	0.624 and 0.450
Refinement method	Full-matrix least-squares on F^2
Data / restraints / parameters	172 / 0 / 13
Goodness-of-fit on F^2	1.457
Final R indices [$I > 2\sigma(I)$]	$R1 = 0.0218, wR2 = 0.0463$
R indices (all data)	$R1 = 0.0272, wR2 = 0.0484$
Extinction coefficient	0.0072(6)
Largest diff. peak and hole	0.634 and -0.705 e/Å ³

Table 4

Atomic co-ordinates and isotropic displacement parameters (pm^2) for Ce_2CoSi_3 with U_{eq} defined as one third of the trace of the diagonalised U_{ij} tensor.

Atom	Wyckoff Site	x	y	z	U_{eq}
Ce(1)	1a	0	0	0	47(3)
Ce(2)	3f	0.5	0	0	56(2)
Co	2d	1/3	2/3	0.5	114(4)
Si	6m	0.1702(1)	0.3403(2)	0.5	67(5)

Table 5

Interatomic distances in Ce_2CoSi_3 up to 3.5Å for Ce-Co, Ce-Si, Co-Si and Si-Si distances and 4.2Å for Ce-Ce distances. Standard deviations are all 0.002Å or less.

Ce1:	12 Si	3.178	Ce2:	8 Si	3.125	Si:	1 Co	2.292
	6 Ce2	4.052		4 Co	3.143		2 Si	2.387
	2 Ce1	4.197		2 Ce1	4.052		4 Ce	3.125
				4 Ce2	4.052		2 Ce	3.178
Co:	3 Si	2.292		2 Ce2	4.197			
	6 Ce2	3.143						

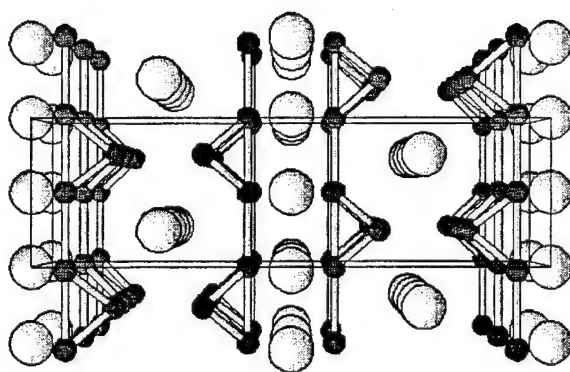
Table 6

Summary of magnetic data on Ce_2TSi_3 (T = transition metals) materials examined by magnetic susceptibility.

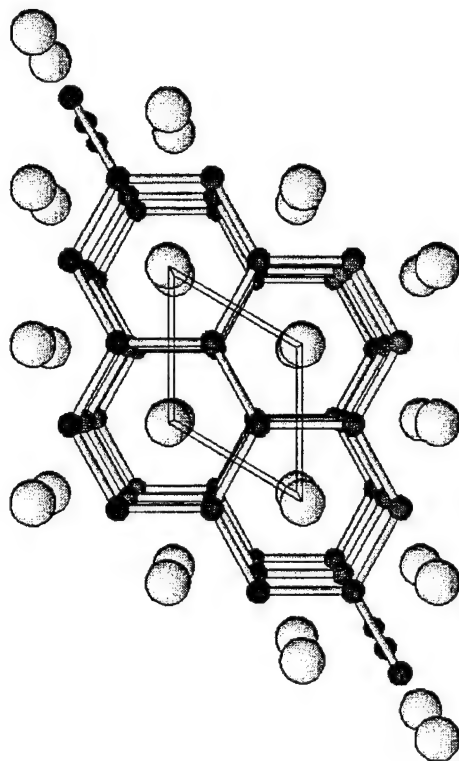
Material	fit range/K	μ/μ_B	θ/K	χ_0 (10^{-3} emu/mol Ce)
$\text{Ce}_2\text{Co}_x\text{Pd}_{1-x}\text{Si}_3$				
x = 0	100-300	2.48(2)	7(1)	0.13(5)
x = 0.5	70-320	2.46(3)	-32(2)	0.21(4)
x = 0.8	100-300	2.50(2)	-82(2)	0.24(4)
Ce_2NiSi_3	80-300	2.48(1)	-22(2)	0.19(5)
$\text{Ce}_2\text{Co}_x\text{Au}_{1-x}\text{Si}_3$				
x = 0.2	80-315	2.48(2)	-5(2)	0.08(6)
x = 0.5	80-320	2.44(1)	-9(1)	0.18(5)
x = 0.6	80-320	2.42(5)	-16(4)	0.23(6)
x = 0.8	80-300	2.35(4)	-42(4)	0.36(7)
x = 0.9	80-340	2.45(11)	-107(13)	0.3(1)

Figure Captions

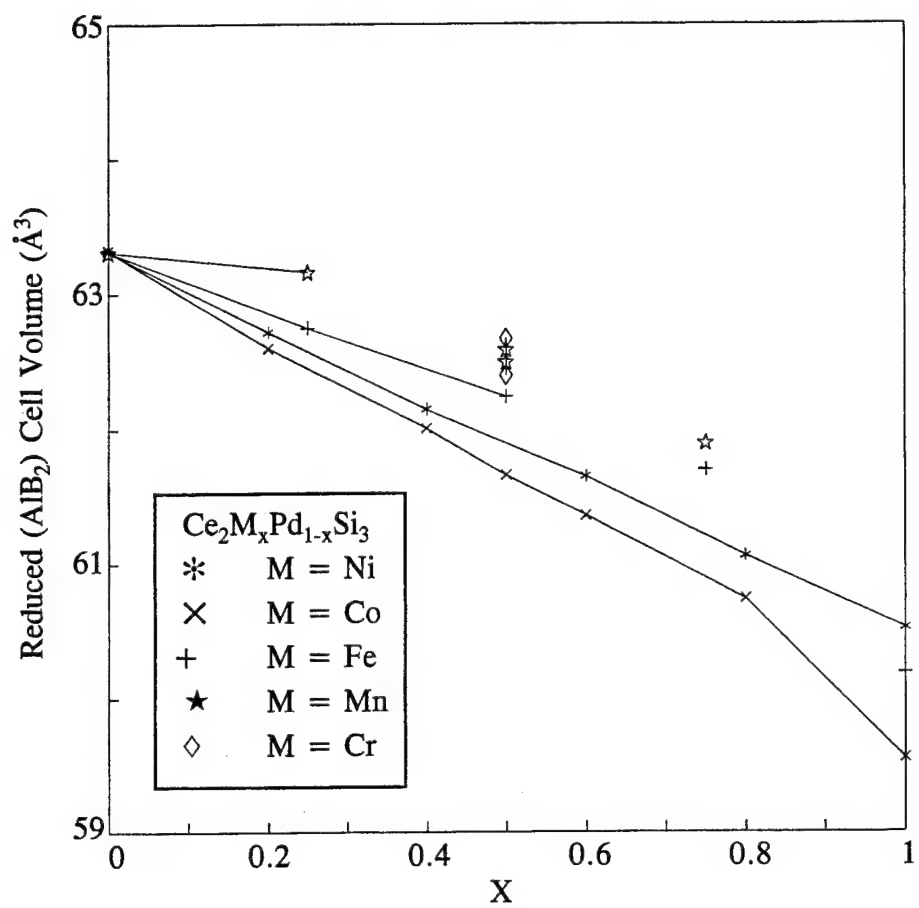
- Figure 1. Perspective views [9] of the structures of (a) α -ThSi₂ and (b) β -ThSi₂, also called the AlB₂ structure type. Large white spheres are Th and the small, grey spheres are Si.
- Figure 2. Dependence of reduced AlB₂ cell volume on M = 3d transition element content for Ce₂M_xPd_{1-x}Si₃ compositions. Lines connect compositions with less than 10% estimated impurity content.
- Figure 3. Dependence of reduced AlB₂ cell volume on M = 3d transition element content in Ce₂M_xAu_{1-x}Si₃ compositions. Lines connect compositions with less than 10% estimated impurity content.
- Figure 4. Perspective view of the unit cell of Ce₂CoSi₃ with adjoining atoms in the CoSi₃ network. Lighter large spheres are cerium atoms marking the corners of the unit cell. Dark medium spheres in the network are cobalt atoms.
- Figure 5. Inverse magnetic susceptibility of Ce₂PdSi₃ from 4.2K to 300K.
- Figure 6. Resistivity of Ce₂PdSi₃ from 4.2K to 300K.
- Figure 7. Temperature dependence of the inverse magnetic susceptibilities for several Ce₂Co_xPd_{1-x}Si₃ compositions and Ce₂NiSi₃.
- Figure 8. Temperature dependence of the inverse magnetic susceptibilities of Ce₂Co_xAu_{1-x}Si₃ compositions.
- Figure 9. Temperature dependence of the resistance of Ce₂CoSi₃. Cracks in the sample prevent determination of an absolute resistivity.
- Figure 10. Specific heat divided by temperature as a function of the square of the temperature from 1.178K to 20K.

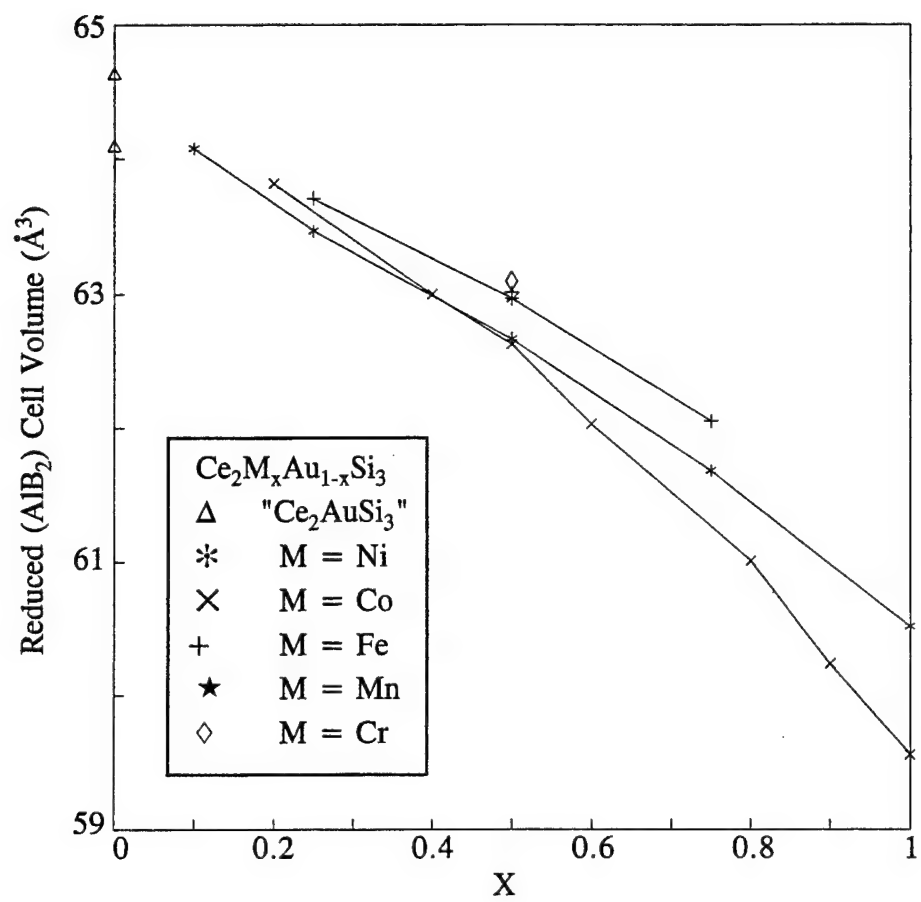


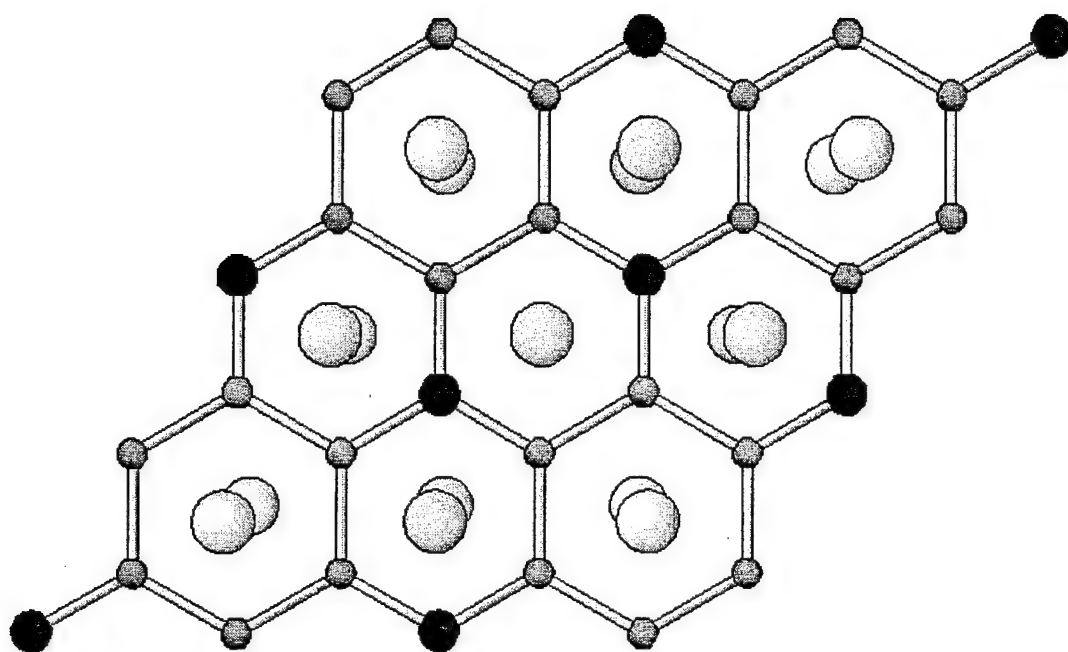
(a) α -ThSi₂

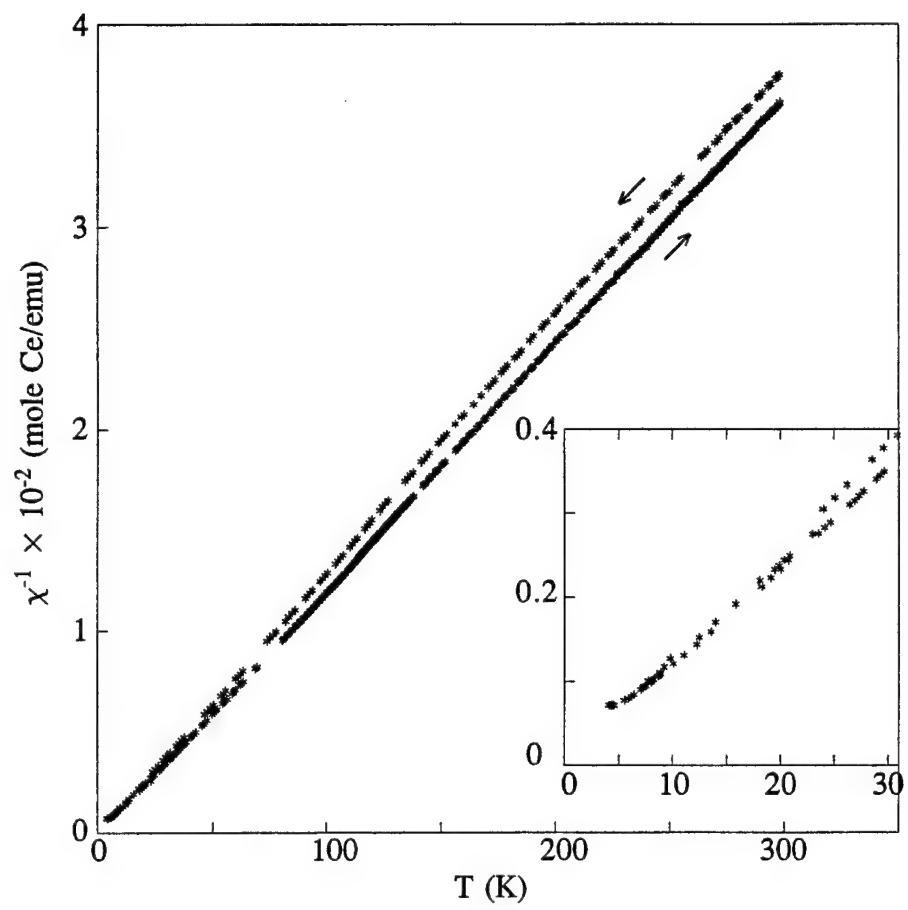


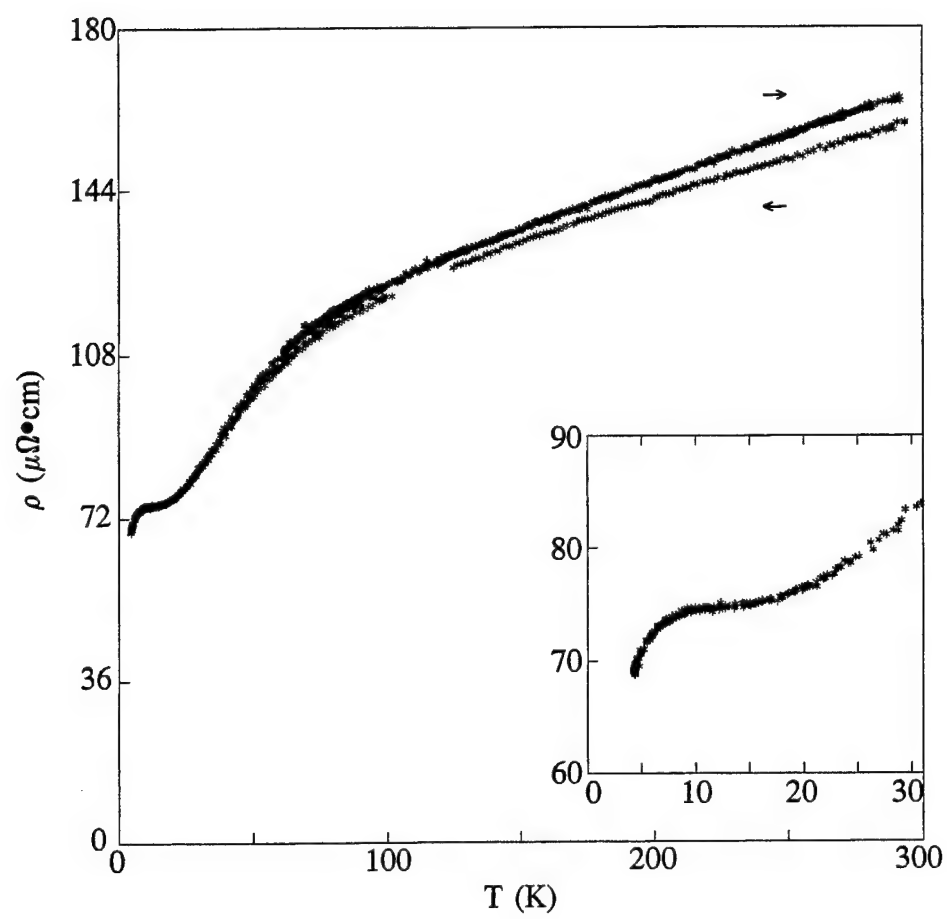
(b) β -ThSi₂ (AIB₂)

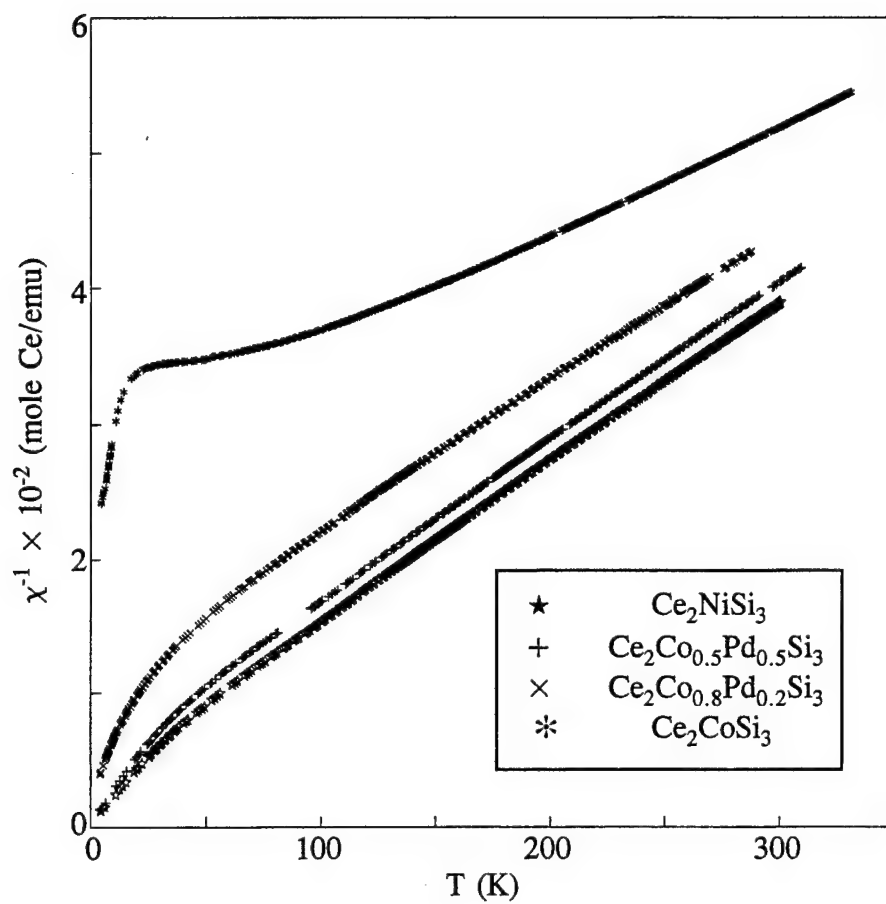


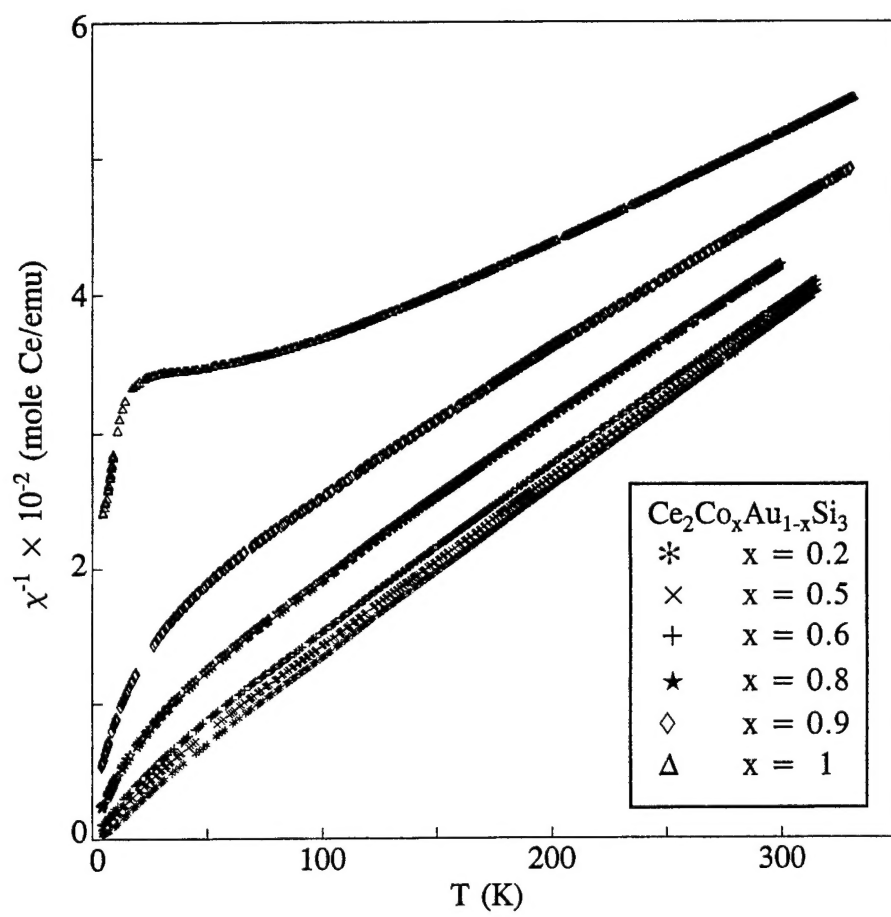


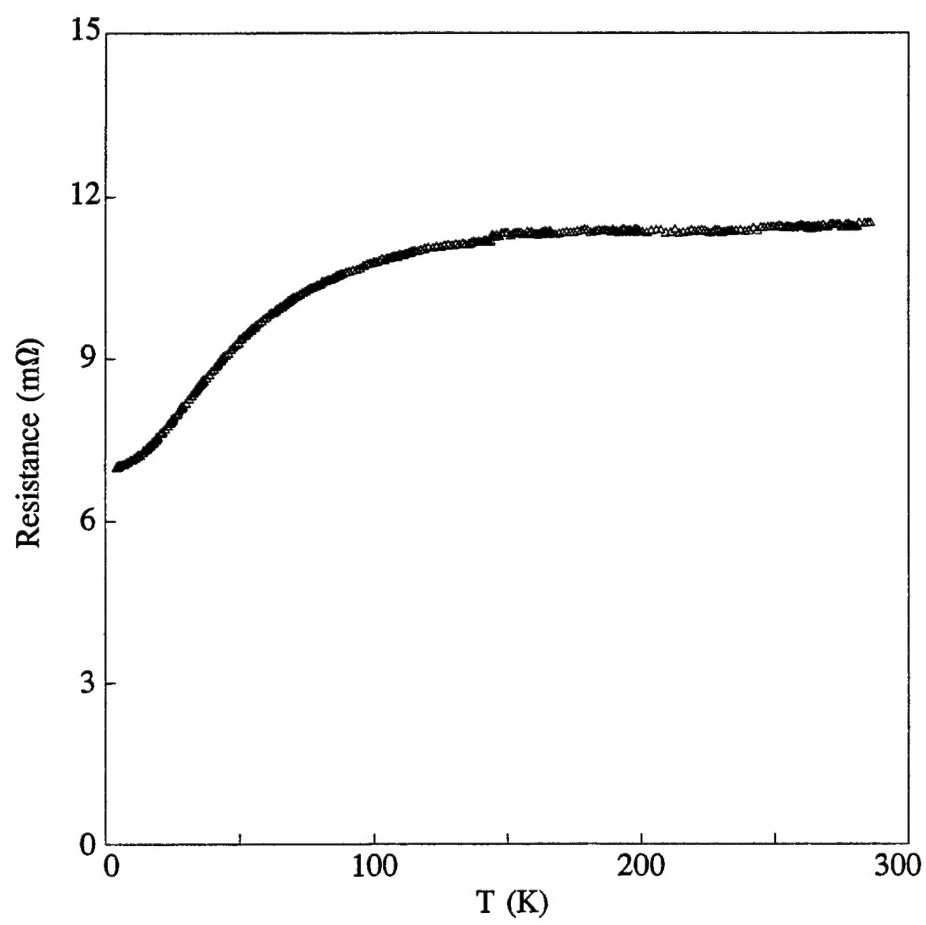


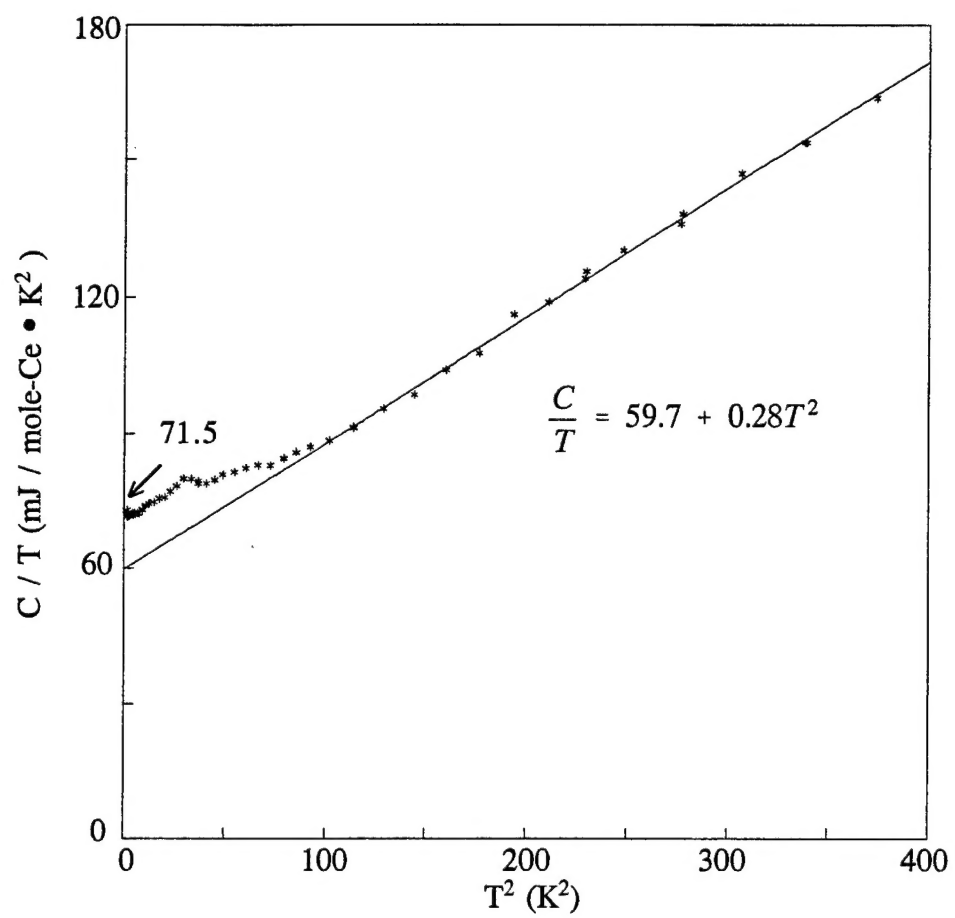












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